

 $\begin{array}{c} R1 \cong 10 k \Omega \\ R2 \cong 0.6 k \Omega \end{array}$

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Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage : TIP110	60	V
	: TIP111	80	V
	: TIP112	100	V
	Collector-Emitter Voltage : TIP110	60	V
V _{CEO}	: TIP111	80	V
	: TIP112	100	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	2	A
I _{CP}	Collector Current (Pulse)	4	A
IB	Base Current (DC)	50	mA
P _C	Collector Dissipation (T _a =25°C)	2	W
	Collector Dissipation (T _C =25°C)	50	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

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* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

November 2008

TIP110/TIP111/TIP112 **NPN Epitaxial Silicon Darlington Transistor**

Monolithic Construction With Built In Base-Emitter Shunt Resistors •

• Complementary to TIP115/116/117

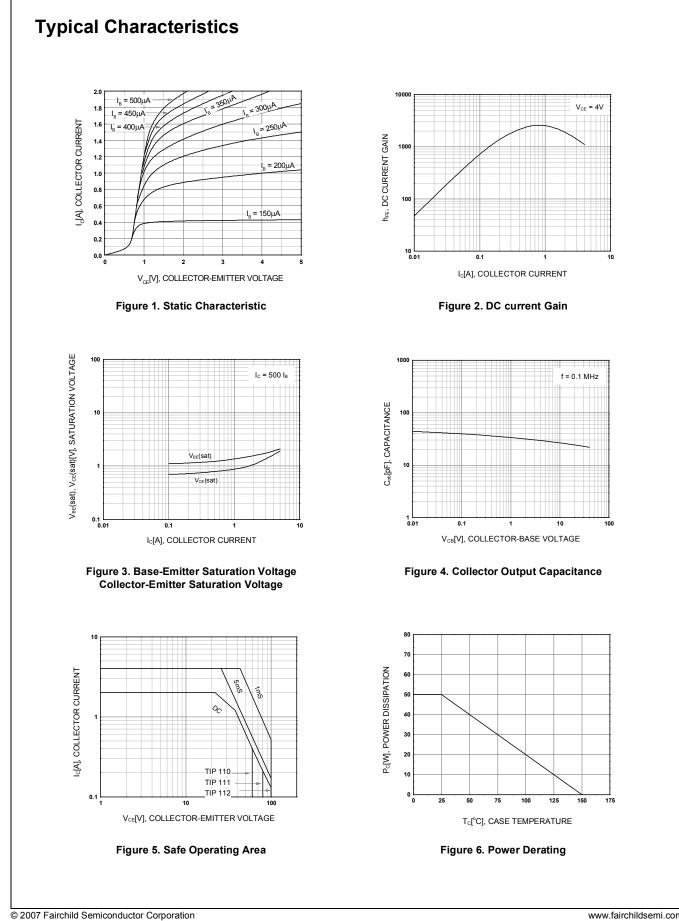
FAIRCHILD

SEMICONDUCTOR®

- High DC Current Gain : h_{FE}=1000 @ V_{CE}=4V, I_C=1A(Min.) •
- Low Collector-Emitter Saturation Voltage
- Industrial Use

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage					
	: TIP110	I _C = 30mA, I _B = 0	60			V
	: TIP111	-	80			V
	: TIP112		100			V
I _{CEO}	Collector Cut-off Current					
	: TIP110	$V_{CE} = 30V, I_{B} = 0$			2	mA
	: TIP111	$V_{CE} = 40V, I_{B} = 0$			2	mA
	: TIP112	$V_{CE} = 50V, I_{B} = 0$			2	mA
I _{CBO}	Collector Cut-off Current					
	: TIP110	V _{CB} = 60V, I _E = 0			1	mA
	: TIP111	$V_{CB} = 80V, I_E = 0$			1	mA
	: TIP112	V _{CB} = 100V, I _E = 0			1	mA
I _{EBO}	Emitter Cut-off Current	V _{BE} = 5V, I _C = 0			2	mA
h _{FE}	DC Current Gain	V _{CE} = 4V, I _C = 1A	1000			
		V_{CE} = 4V, I_{C} = 2A	500			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 2A, I _B = 8mA			2.5	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} = 4V, I _C = 2A			2.8	V
C _{ob}	Output Capacitance	V _{CB} = 10V, I _E = 0, f = 0.1MHz			100	pF

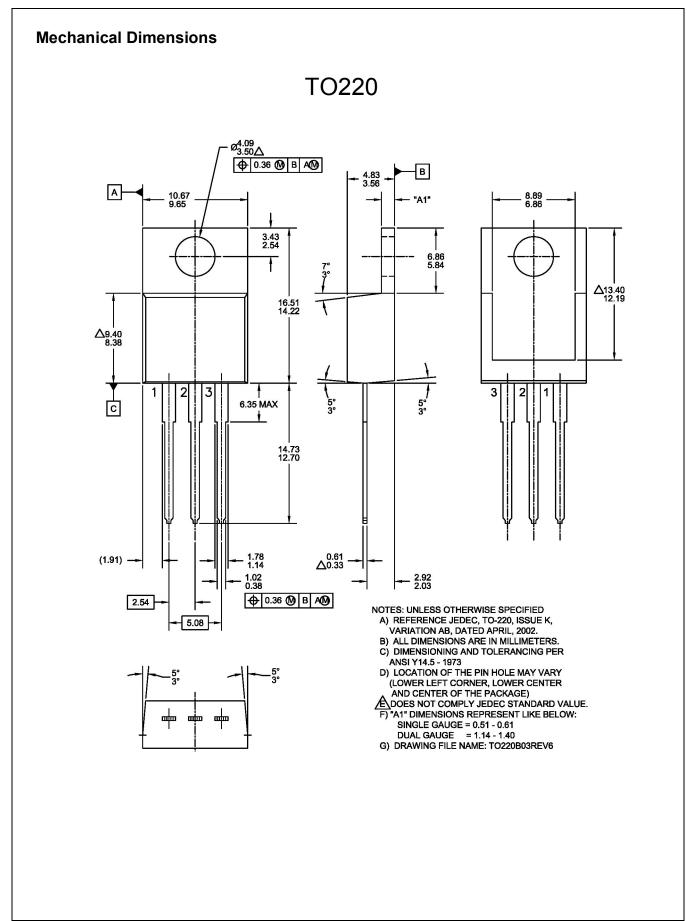
* Pulse Test: Pulse Width≤300µs, Duty Cycle≤2%



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TIP110/TIP111/TIP112 Rev. 1.0.0

TIP110/TIP111/TIP112 — NPN Epitaxial Silicon Darlington Transistor





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